

ULTRA FAST RECTIFIER

VOLTAGE RANGE: 50 --- 1000 V
CURRENT: 1.0 A

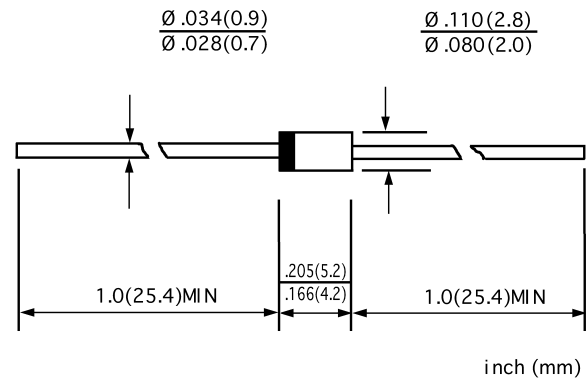
FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with freon, alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO-41, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.012 ounces, 0.34 grams
- ◇ Mounting position: Any

DO - 41



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		UF4001	UF4002	UF4003	UF4004	UF4005	UF4006	UF4007	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 9.5mm lead length, @T _A =75°C	I _{F(AV)}	1.0							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @T _J =125°C	I _{FSM}	30.0							A
Maximum instantaneous forward voltage @ 1.0A	V _F	1.0				1.7			V
Maximum reverse current @T _A =25°C at rated DC blocking voltage @T _A =100°C	I _R	10.0 100.0							μ A
Maximum reverse recovery time (Note1)	t _{rr}	50				75			ns
Typical junction capacitance (Note2)	C _J	17							pF
Typical thermal resistance (Note3)	R _{θJA}	60							°C /W
Operating junction temperature range	T _J	- 55 ----- + 150							°C
Storage temperature range	T _{STG}	- 55 ----- + 150							°C

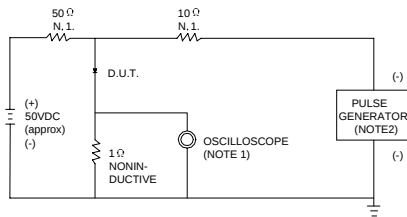
NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $t_{rr}=0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

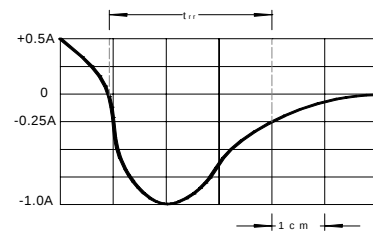
3. Thermal resistance junction to ambient

www.galaxycn.com

FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ .22pF.
2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω .



SET TIME BASE FOR 10/20 ns/cm

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

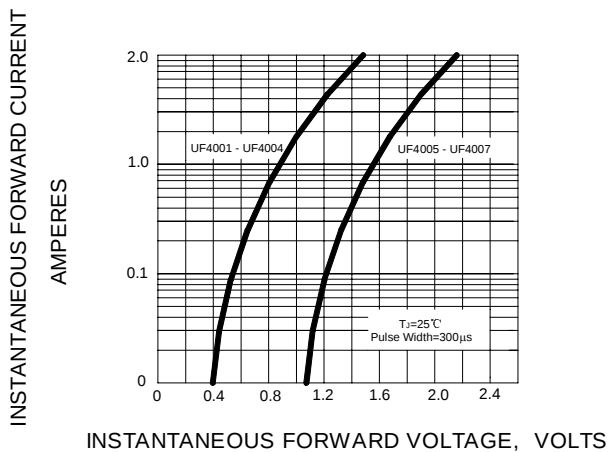


FIG.3 -- FORWARD DERATING CURVE

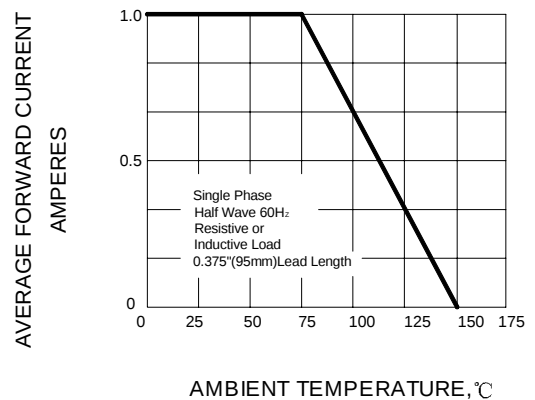


FIG.4 -- TYPICAL JUNCTION CAPACITANCE

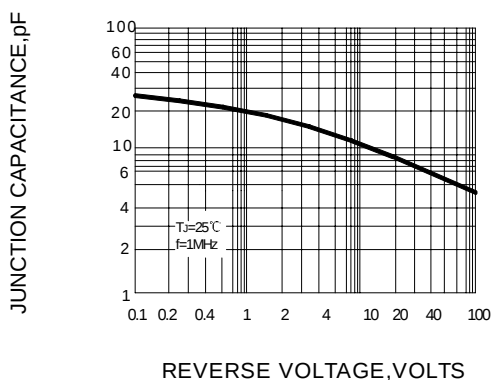


FIG.5 -- PEAK FORWARD SURGE CURRENT

